

## **Switchmode Dual Fast Recovery Power Rectifiers**

... Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- \* Glass Passivated chip junctions
- \* Low Reverse Leakage Current
- \* Fast Switching for High Efficiency
- \* 150 °C Operating Junction Temperature
- \* Low Forward Voltage , High Current Capability
  \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \*In compliance with EU RoHs directives



## **MAXIMUM RATINGS**

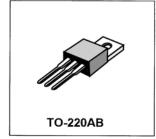
Characteristic	Symbol	F12C				Unit
		30	40	50	60	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	300	400	500	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	210	280	350	420	٧
Average Rectifier Forward Current Per Leg T <sub>c</sub> =125°C Per Total Device	I <sub>F(AV)</sub>	6.0 12			Α	
Peak Repetitive Forward Current (Rate V <sub>R</sub> ,Square Wave,20kHz,T <sub>c</sub> =125°C)	I <sub>FM</sub>	12			Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	FSM	80			А	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 65 to + 150		°C		

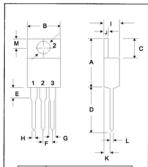
## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	F12C				Unit
		30	40	50	60	
Maximum Instantaneous Forward Voltage ( $I_F$ =6.0 Amp, $T_c$ = 25 $^{\circ}$ C)	V <sub>F</sub>	1.30			V	
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_c = 25$ °C) ( Rated DC Voltage, $T_c = 125$ °C)	I <sub>R</sub>	5.0 100			uA	
Reverse Recovery Time (I <sub>F</sub> = 0.5 A, I <sub>R</sub> =1.0 , I <sub>rr</sub> =0.25 A)	Т"	250			ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)		4	15		30	pF

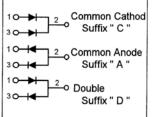
**FAST RECOVERY RECTIFIERS** 

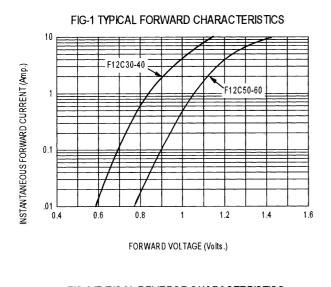
12 AMPERES 300 -- 600 VOLTS

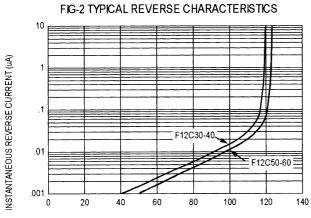


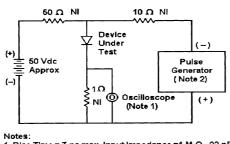


DIM	MILLIM	MILLIMETERS		
DIIVI	MIN	MAX		
Α	14.68	16.00		
В	9.78	10.42		
С	5.02	6.60		
D	13.00	14.62		
E	3.10	4.19		
F	2.41	2.67		
G	1.10	1.67		
н	0.69	1.01		
1	3.21	4.98		
J	1.14	1.40		
K	2.20	3.30		
L	0.28	0.61		
M	2.48	3.00		
0	3.50	4.00		

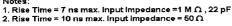


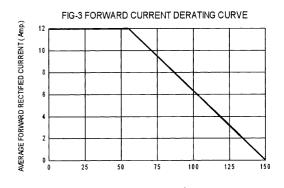


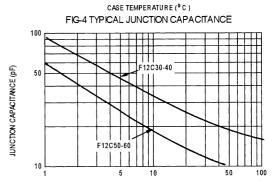


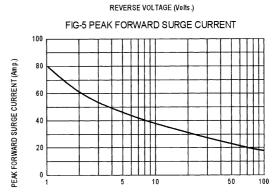


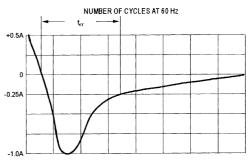
PERCENT OF PEAK REVERSE VOLTAGE(%)











Set time base for 50/100 ns/div

Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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